



#### 1A DUAL COMMON CATHODE SCHOTTKY BARRIER DIODE DIE SIZE PACKAGE

#### **Product Summary**

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F</sub> Max (V) @ +25°C	I <sub>R</sub> Max (μA) @ +25°C
20	1	0.50	100

## **Description and Applications**

The SDM1L20DCP3 is a 20V Dual Common Cathode Schottky Barrier Diodes that is optimized for very low forward voltage drop and low leakage current. It's housed in a compact die size package that occupies only 0.6mm<sup>2</sup> board space with low profile. The low thermal resistance enables designers to meet design challenges of increasing efficiency while reducing board space. It is ideally suited for use in portable applications such as:

- Blocking Diode
- Reverse Protection Diode
- Boost Diode

#### **Features and Benefits**

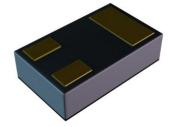
- 0.6mm<sup>2</sup> Footprint, Off Board Profile of 0.275mm
- Low Forward Voltage Minimizes Power Dissipation Losses
- Low Leakage Maximizes Battery Power
- Soft, Fast Switching Capability
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

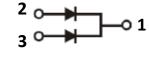
#### **Mechanical Data**

- Case: X3-DSN1006-3
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity Indicator: Cathode Dot
- Terminals: NiAu Bump. Solderable per MIL-STD-202, Method 208 @4)
- Weight: 0.1mg (Approximate)









Top View

**Bottom View** 

### Ordering Information (Note 4)

Part Number	Case	Packaging
SDM1L20DCP3-7	X3-DSN1006-3	5,000/Tape & Reel

Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



XC = Product Type Marking Code YM = Date Code Marking Y or Y = Year (ex: G = 2019) M = Month (ex: 9 = September) Bar Denotes Cathode Pin

Date Code Key

Year	201	6	2017		2018	20	19	2020		2021	2	2022
Code	D		Е		F		3	Н		ı		J
Month	lon	Feb	Man	A				A	0	0-1	NI	D
WOITH	Jan	reb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	20	V
Average Rectified Output Current (Total)	lo	1	Α
Repetitive Peak Forward Current, $t_p \le 1$ ms; $\delta \le 0.25$ (Single Diode)	I <sub>FRM</sub>	3	А
Non-Repetitive Peak Forward Surge Current, 8.3ms Single Half Sine-Wave Superimposed on Rated Load (Single Diode)	I <sub>FSM</sub>	10	А
ESD Rating Human Body Model Charged Device Model	ESD	8 1	kV

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{ heta JA}$	245	°C/W
Typical Thermal Resistance Junction to Ambient (Note 6)	$R_{ heta JA}$	105	°C/W
Operating Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

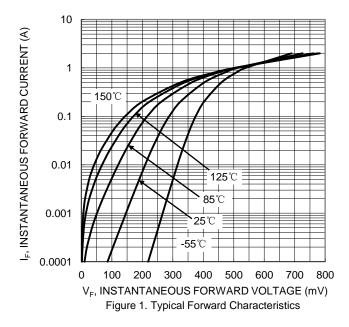
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

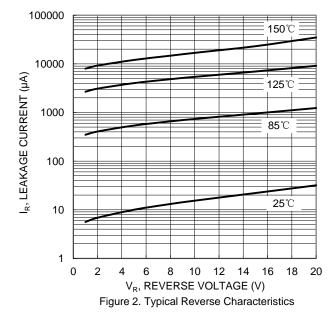
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
	VF	_	210	260	mV	I <sub>F</sub> = 10mA, T <sub>J</sub> = +25°C
Familiard Make as Dress (Girarla Diada)		_	290	350		I <sub>F</sub> = 100mA, T <sub>J</sub> = +25°C
Forward Voltage Drop (Single Diode)		_	330	400		$I_F = 200 \text{mA}, T_J = +25 ^{\circ}\text{C}$
		1	420	500		$I_F = 500 \text{mA}, T_J = +25 ^{\circ}\text{C}$
Leakage Current (Note 7) (Single	I <sub>R</sub>	_	15	50	μA	V <sub>R</sub> = 10V, T <sub>J</sub> = +25°C
Diode)		_	32	100	μΑ	$V_R = 20V, T_J = +25^{\circ}C$
Junction Capacitance (Single Diode)	CJ	_	18	_	pF	$V_R = 5V, T_J = +25^{\circ}C, f = 1MHz$
Reverse Recovery Time (Single Diode)	t <sub>RR</sub>		8.6		ns	$I_F = 10 \text{mA}, I_{RR} = 0.1 \times I_R$

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz Cu with minimum recommended pad layout per http://www.diodes.com/package-outlines.html.
- 6. Device mounted on FR-4 substrate PC board, 1 inch square 2oz Cu pad.
- 7. Short duration pulse test used to minimize self-heating effect.







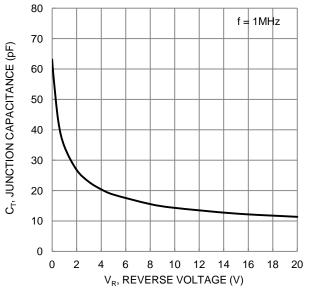
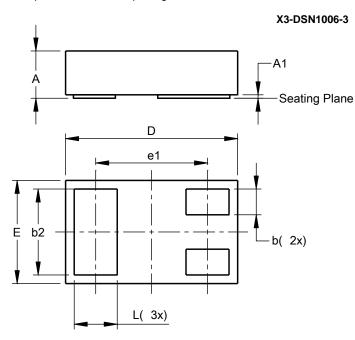


Figure 3. Typical Junction Capacitance



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

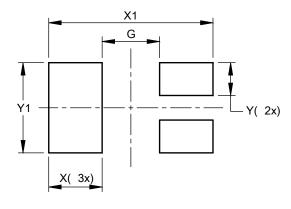


X3-DSN1006-3						
Dim	Min	Max	Тур			
Α	0.250	0.300	0.275			
A1	0.00	0.02	0.01			
b	0.130	0.170	0.150			
b2	0.480	0.520	0.500			
D	0.960	1.040	1.00			
Е	0.560	0.640	0.600			
е			0.350			
e1			0.650			
L	0.230	0.270	0.250			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X3-DSN1006-3



Dimensions	Value (in mm)
G	0.350
Х	0.325
X1	1.00
Υ	0.200
Y1	0.550



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